EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	880	"Yamazaki" and "electroluminescence" and "TFT"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:22
L2	376	"Yamazaki" and "electroluminescence" and storage with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:34
L3	154	@ad<="20000302" and "electroluminescence" and storage with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:34
L4	843	@ad<="20000302" and (257/72).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:49
L5	210	@ad<="20000302" and (257/69).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 09:02
L6	422	@ad<="20000302" and (257/79).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:49
L7	715	@ad<="20000302" and (257/40).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:49
L8	100	@ad<="20000302" and (257/83).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:49
L9	477	@ad<="20000302" and (257/88).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:49
L10	7851	@ad<="20000302" and (257/351).ccls. or (257/E21.413).ccls. or (257/E21.703).ccls. or (257/E27.111).ccls. or (257/E29.147).ccls. or (257/E29.151).ccls. or (257/E29.278).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:55

L11	194	@ad<="20000302" and (349/111). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:59
L12	174	@ad<="20000302" and (349/39). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:59
L13	994	@ad<="20000302" and (257/59). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 09:02
S1	2	("6677613").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/10/21 11:08
S2	2	"20040036071"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 11:08
S3	1	"5463483".PN.	USPAT	OR	OFF	2004/10/21 11:23
S4	1	"5594569".PN.	USPAT	OR	OFF	2004/10/21 11:23
S5	1	"5856689".PN.	USPAT	OR	OFF	2004/10/21 11:24
S6	1	"5904514".PN.	USPAT	OR	OFF	2004/10/21 11:25
S7	1	"5998841".PN.	USPAT	OR	OFF	2004/10/21 11:25
S8	1	"6162654".PN.	USPAT	OR	OFF	2004/10/21 11:26
S9	1	"6208392".PN.	USPAT	OR	OFF	2004/10/21 11:26
S10	1	"6271543".PN.	USPAT	OR	OFF	2004/10/21 11:29
S11	704	@ad<="19990303" and (257/72). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:48
S12	385	@ad<="19990303" and (257/79). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 11:55
S13	648	@ad<="19990303" and (257/40). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 11:56

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S14	91	@ad<="19990303" and (257/83).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 11:56
S15	450	@ad<="19990303" and (257/88).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 11:56
S16	261	@ad<="19990303" and 'liquid crystal display' and 'transistor' and 'light shielding layer' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 08:26
S17	34	@ad<="19990303" and 'liquid crystal display' and 'transistor' and 'light shielding layer' and 'pixel electrode' and 'storage capacitance'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 09:57
S18	1812	@ad<="19990303" and (345/87).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 12:02
S19	537	@ad<="19990303" and (345/92).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 12:05
S20	998	@ad<="19990303" and (345/102-104).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 12:04
S21	784	@ad<="19990303" and (345/94).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:11
S22	1	"6157429".PN.	USPAT	OR	OFF	2004/10/21 13:05
S23	1	"6127998".PN.	USPAT	OR	OFF	2004/10/21 13:06
S24	1	"5827755".PN.	USPAT	OR	OFF	2004/10/21 13:06
S25	1	"5815223".PN.	USPAT	OR	OFF	2004/10/21 13:07
S26	1	"5691794".PN.	USPAT	OR	OFF	2004/10/21 13:09
S27	1	"5591990".PN.	USPAT	OR	OFF	2004/10/21 13:10
S28	1	"5200926".PN.	USPAT	OR	OFF	2004/10/21 13:11
S29	1282	@ad<="19990303" and (349/42).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:58

S30	1625	@ad<="19990303" and (349/139)".ccls"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:14
S31	1011	@ad<="19990303" and (349/138)".ccls"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:15
S32	1360	@ad<="19990303" and (349/158)".ccls"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:17
S33	130	@ad<="19990303" and (349/145)".ccls"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:27
S34	108	@ad<="19990303" and (368/30)".ccls"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:51
S35	3	@ad<="19990303" and 'electro-optical device' and 'silicon substrate' and 'active matrix pixel'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:53
S36	14	@ad<="19990303" and 'LCD' and 'silicon substrate' and 'resin' and 'shielding layer' and 'pixel'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 13:54
S37	3	@ad<="19990303" and 'silicon substrate' and 'transistor' and 'light shielding layer' and 'pixel electrode' and 'storage capacitance'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 14:56
S38	79	@ad<="19990303" and 'dielectric' same 'SiO' same 'polyimide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 14:58
S39	45	@ad<="19990303" and 'dielectric' same 'SiO' with 'polyimide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 15:15
S40	74	@ad<="19990303" and 'dielectric' with 'SOG' with 'polyimide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 15:05

S41	6	@ad<="19990303" and 'dielectric' with 'SOG' with 'BCB'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 15:07
S42	1	@ad<="19990303" and 'dielectric' same 'SOG' same 'P' adj1 'SiO'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 15:08
S43	5	@ad<="19990303" and 'dielectric' same 'P' adj1 'SiO'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 15:09
S44	1	@ad<="19990303" and 'dielectric' same 'SiO' with 'BCB'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/21 15:16
S45	14	@ad<="19990303" and 'dielectric' same 'SiO' with 'polyamide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/22 09:20
S46	1	@ad<="19990303" and 'dielectric' same 'PSG' with 'BPSG' with 'BCB'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/22 09:21
S47	1	@ad<="19990303" and 'dielectric' same 'PSG' with 'BCB'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/22 09:21
S48	61	@ad<="19990303" and 'dielectric' with 'PSG' with 'polyimide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/10/22 09:34
S49	2	("6157429").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/10/22 09:34
S50	2	("6583057").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/24 07:36

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S51	16	@ad<="19990303" and 'SOI' and 'LCD' and 'transistor' and 'light shielding' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 11:30
S52	30	@ad<="20000302" and 'SOI' and 'LCD' and 'transistor' and 'light shielding' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 08:58
S53	25	@ad<="20000302" and 'SOI' and 'LCD' and 'resin' and 'light shielding' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 08:40
S54	6	@ad<="20000302" and 'SOI' and 'LCD' and 'resin' and 'FET' and 'light shielding' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 08:42
S55	14	@ad<="20000302" and 'SOI' and 'transistor' and 'organic' and 'storage capacitor' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 08:43
S56	2	@ad<="20000302" and 'SOI' and 'LCD' same 'FET' and 'pixel electrode'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 09:10
S57	0	@ad<="20000302" and 'SOI' with 'display' same 'FET' and 'pixel'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 09:11
S58	0	@ad<="20000302" and 'SOI' same 'display' same 'FET' and 'pixel'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 09:11
S59	7	@ad<="20000302" and 'SOI' and 'display' same 'FET' and 'pixel'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/24 09:11
S60	1	"6271543".PN.	USPAT; USOCR	OR	ON	2005/02/24 09:11
S61	1	"6208392".PN.	USPAT; USOCR	OR	ON	2005/02/24 09:12
S62	413	Yamazaki-Shunpei.in. and 'organic EL'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 08:54

S63	1	"20040084673".PN.	US-PGPUB	OR	ON	2005/06/29 08:46
S64	1	"20030057419".PN.	US-PGPUB	OR	ON	2005/06/29 08:47
S65	343	Yamazaki-Shunpei.in. and 'organic EL' and 'switching' and 'controlling'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 09:25
S66	1	"6281552".PN.	USPAT; USOCR	OR	ON	2005/06/29 09:01
S67	1	"6271543".PN.	USPAT; USOCR	OR	ON	2005/06/29 09:09
S68	1	"6208392".PN.	USPAT; USOCR	OR	ON	2005/06/29 09:12
S69	1	"6162654".PN.	USPAT; USOCR	OR	ON	2005/06/29 09:12
S70	1	"5998841".PN.	USPAT; USOCR	OR	ON	2005/06/29 09:13
S71	25	@ad<="20000302" and Yamazaki-Shunpei.in. and 'organic EL' and 'switching' and 'controlling'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 09:40
S72	4	@ad<="20000302" and 'organic EL' and 'switching transistor' and 'controlling transistor'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 09:40
S73	23	@ad<="20000302" and 'organic EL' and 'transistor' and 'controlling' with 'power'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 09:41
S74	33	@ad<="20000302" and 'organic EL' and 'transistor' and 'controlling' same 'power'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:39
S75	1	"6246384".PN.	USPAT; USOCR	OR	ON	2005/06/29 09:51
S76	32	@ad<="20000302" and 'organic EL' and 'switching' and 'controlling' same 'power'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:12
S77	4	(("6781155") or ("6836067")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/29 10:54

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S78	99	@ad<="19990303" and 'SOI' and 'LCD' and 'P-channel'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 11:30
S79	1	"5962845".PN.	USPAT; USOCR	OR	ON	2005/06/29 11:40
S80	1	"5940058".PN.	USPAT; USOCR	OR	ON	2005/06/29 11:41
S81	0	@ad<="20000302" and 'organic EL' and 'switching' and 'controlling' and 'light shield electrode' with 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:14
S82	2	@ad<="20000302" and 'organic EL' and 'switching' and 'controlling' and 'light shielding' with 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:14
S83	3	@ad<="20000302" and 'organic EL' and 'light shielding' with 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:16
S84	6	@ad<="20000302" and 'organic EL' and 'light shielding' same 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:22
S85	165	@ad<="20000302" and 'light shielding' same 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:23
S86	7	@ad<="20000302" and 'EL' and 'light shielding' same 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:28
S87	20	@ad<="20000302" and 'LCD' and 'shielding' same 'oxidation'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:48
S88	186	@ad<="20000302" and 'light shielding' and 'black mask'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 13:51
S89	8	@ad<="20000302" and 'valve metal' and 'LCD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 15:34

S90	28	@ad<="20000302" and 'valve metal' and 'EL'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 15:34
S91	2	"20010022565"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:36
S94	1124	('apparatus' and 'smooth' and 'chamber' 'beam of particle' and 'energy').clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 17:07
S95	858	('apparatus' and 'smooth' and 'surface' and 'chamber' 'beam of particle' and 'low energy').clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 17:08
S96	48	('apparatus' and 'smoothing' with 'surface' and 'chamber' 'beam of particle' and 'low energy').clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 17:16
S97	0	('apparatus' and 'smoothing' with 'surface' and 'chamber' and 'beam of particle' and 'low energy').clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 17:16
S98	4	('apparatus' and 'smoothing' with 'surface' and 'beam' with 'particle' and 'low energy').clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 17:16
S100	770	@ad<="20000302" and 'TFT' same 'substrate' with 'semiconductor' with 'glass'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 06:44
S101	567	@ad<="20000302" and 'TFT' with 'substrate' with 'semiconductor' with 'glass'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 07:29
S102	15	@ad<="20000302" and 'TFT' with 'glass substrate' with 'semiconductor substrate'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 07:29
S103	737	@ad<="20000302" and ("electroluminescence" or "EL") and "transistor" and "storage" with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 13:38

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S104	237	@ad<="20000302" and ("electroluminescence" or "EL") and (switch$3 same control$3 same "transistor") and "storage" with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 10:26
S105	2	("20010022565").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/02 10:13
S106	122	@ad<="20000302" and ("electroluminescence" or "EL") same storage with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 10:27
S107	86	@ad<="20000302" and ("electroluminescence" or "EL") and "switching transistor" and "control transistor"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 13:41
S108	232	@ad<="20000302" and ("electroluminescence" or "EL") and "CMOS" and "storage" with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 13:42
S109	147	@ad<="20000302" and ("electroluminescence" or "EL") and ("CMOS" or "TFT") same "storage" with capacit$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 13:44
S110	26	@ad<="20000302" and ("electroluminescence" or "EL") and ("CMOS" or "TFT") same "storage capacitance"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:13
S111	66	"Yamazaki" and "electroluminescence" and "TFT" and "storage capacitance"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/03 08:20
S112	119	Yamazaki-shunpei.in. and "TFT" and "storage capacitance"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/02 16:14

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